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3. REPORT TYPE AND DATES COVERED 12. REPORT DATE

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January 1991

Final Report 10/1/86-09/3090

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Structure and Properties of Novel Compounds of

Silicon, Germanium and Tin

S. FUNDING NUMBERS

61102F 2303 B2

PROPERTY ORGANIZATION NAME(S) AND ADDRESS(ES)

University of Texas P.O. Box 7726 Austin, TX 78713-7726 8. PERFORMING ORGANIZATION REPORT NUMBER

AEOSR-TR

91 0173

9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES)

AFOSR/NC

Building 410; Bolling AFB DC & C.

10. SPONSORING/MONITORING
... AGENCY REPORT NUMBER

AFOSR-87-0001

11. SUPPLEMENTARY NOTES

MAR LS 1991

12a, DISTRIBUTION/AVAILABILITY STATEMENT

APPROVED FOR PUBLIC RELEASE; DISTRIBUTION IS UNLIMITED.

12b. DISTRIBUTION CODE

13. ABSTRACT (Maximum 200 words).

We have concentrated our efforts on the spectroscopy, photophysics, and photochemistry of polysilanes, using a combination of experimental and theoretical tools. We have developed a more detailed version of the chain segment model, have identified and thoroughly characterized the persistent radical formed in UV photolysis, documented further the recently uncovered process of photoinnuced chain scission by reductive elimination, and advanced the theoretical understanding of the electronic states of model short-chain oligosilanes. The combined results suggest strongly that the shorter chromophoric chain segments have a different lowest excited singlet state (on*) than the longer ones (oo*). Confirming evidence for this is still being sought. The second control of the second control of

14. SUBJECT TERMS

15. NUMBER OF PAGES

16. PRICE CODE

UNCLASSIFIED

17. SECURITY CLASSIFICATION 18. SECURITY CLASSIFICATION UNCLASSIFIED

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I 19. SECURITY CLASSIFICATION OF ABSTRACE

UNCLASSIFIED

20. LIMITATION OF ABSTRACT

ISN 7540-01-280-5506

Standard Form 298 (Rev. 2-89)

Technical Report

STRUCTURE AND PROPERTIES OF NOVEL COMPOUNDS OF SILICON, GERMANIUM AND TIN

The Air Force Office of Scientific Research
Air Force Systems Command

Contract No. 87-0001

Principal Investigator

Josef Michl
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The University of Texas
Austin, TX 78712-1167

Period Covered: October 1, 1989 - September 30, 1990

ABSTRACT

We have concentrated our efforts on the spectroscopy, photophysics, and photochemistry of polysilanes, using a combination of experimental and theoretical tools. We have developed a more detailed version of the chain segment model, have identified and thoroughly characterized the persistent radicals formed in UV photolysis, documented further the recently uncovered process of photoinduced chain scission by reductive elimination, and advanced the theoretical understanding of the electronic states of model short-chain oligosilanes. The combined results suggest strongly that the shorter chromophoric chain segments have a different lowest excited singlet state $(\sigma \pi^*)$ than the longer ones $(\sigma \sigma^*)$. Confirming evidence for this is still being sought.

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Lectures Given Which Acknowledge Support of AFOSR 87-0001

- 4th International Conference on Unconventional Photoactive Solids, San Jose, CA
- University of Santiago, Santiago, Chile
- XXIII Organosilicon Symposium, Midland, MI
- Symposium on "Key Problems in Silicon Chemistry", University of Colorado, Boulder, CO.
- 13th IUPAC Symposium on Photochemistry, University of Warwick, Coventry, England
- 200th ACS National Meeting, Symposium on Sigma-Conjugated Polymers (ACS/APS jointly sponsored), Washington, DC

The following individuals participated in the work:

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V. Balaji

Ya-Ping Sun

Juliusz G. Radziszewski

A. Publications previously reported:

- Michalczyk, M. J.; Fink, M. J.; Haller, K. J.; West, R.; Michl, J. "Structural and Chemical Properties of 1,3-Cyclodisiloxanes", Organometallics 1986, 5, 531.
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- 3. Vančik, H.; Raabe, G.: Michalczyk, M. J.; West, R.; Michl, J. "Dimethylsilylene: A Trisilane and a Geminal Diazide as New Photochemical Precursors. Evidence for an Absorption Maximum Near 450 nm", J. Am. Chem. Soc. 1985, 107, 4097.
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- B. Publication previously reported as in Press or Submitted that have now appeared:
- 14. Barrau, J.; Bean, D. L.; Welsh, K. M.; West, R.; Michl, J. "Photo-chemistry of a Matrix-isolated Geminal Diazide: Dimethylgermylene", Organometallics 1989, 8, 2606.
- 15. Barrau, J.; Balaji, V.; Michl, J. "Matrix Isolation and IR Spectroscopy of Germanethione Me₂Ge=S", Organometallics, 1989, 8, 2034.
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- 17. Michl, J., "The Relationship of Bonding to Electronic Spectra", Acc. Chem. Res. 1990, 23, 127.
- C. Publications submitted since the last report was written:
- 18. Sun, Y.-P.; Miller, R. D.; Sooriyakumaran, R.; Michl, J. "Fluorescence of Poly(di-n-alkylsilane)s in Room-Temperature Solution", J. Inorg. Organomet. Polym., in press.
- 19. McKinley, A. J.; Karatsu, T.; Wallraff, G. M.; Thompson, D. P.; Miller, R. D.; Michl, J. "Solution Photochemistry of Poly(di-n-alkylsilane)s. An EPR-ENDOR Study of the Structure of the Persistent Radicals", J. Am. Chem. Soc., in press.
- 20. Davidson, I. M. T.; Michl, J.; Simpson, T., "The Photochemistry of Some Permethyloligosilanes", submitted for publication.
- 21. Michl, J.; Balaji, V., "Calculations of Photochemical Reactivity. Oligosilanes as an Illustration" in Computational Advances in Organic Chemistry; Ögretir, C., Csizmadia, I. G., Eds.; Kluwer: Dordrecht, The Netherlands; in press.
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- 23. Miller, R. D.; Michl, J. "Polysilane High Polymers", Chem. Rev. 1989, 89, 1359:
- 24. Miller, R. D.; Wallraff, G.; Clecak, N.; Sooriyakumaran, R.; Michl, J.; Karatsu, T.; McKinley, A. J.; Klingensmith, K. A.; Downing, J., "Polysilanes: Solution Photochemistry and Deep UV Lithography", Polym. Eng. Sci. 1989, 29, 882.

SCIENTIFIC RESULTS

In this period, our work has emphasized oligosilanes and polysilanes, reflecting the intense interest in this area among chemists, physicists and material scientists. We have concentrated on the fundamental aspects (nos. 18-23 on the list of references) but participated also in the exploitation of these materials for deep UV lithography (no. 24 on the list).

We have performed a comprehensive study [18] of the luminescence of polysilanes in room-temperature solution and proposed an improved version of the chain segment model that we published in 1986. We have completed an extensive investigation [19] of the persistent radicals formed by UV irradiation of polysilane solutions and determined their structure, including conformational properties, by EPR, ENDOR, and TRIPLE resonance on a series of isotopically labeled polymers. These now probably are the best characterized polymer-based radicals of any kind. We have proposed plausible mechanisms for the complex chemical transformations involved in the formation of the observed radical products, and assigned a key role to photoinduced chain scission by homolysis and by reductive elimination; while the former had always been taken for granted, we postulated the latter only in 1989. We have now found confirming evidence for the latter from a study of the photochemistry of short-chain oligosilanes [20]. It has thus become clear that at least three primary processes are important in the photodegradation of polysilanes: the two types of chain scission, and the chain abridgement by silylene extrusion, described by Trefonas, West and Miller in 1985.

We have obtained satisfactory theoretical descriptions of all three primary processes by means of ab initio computations on model oligosilanes [21]. We have used this theoretical tool to investigate the excited electronic states in fair amount of detail [21, 22] and obtained a picture in which the photophysical and photochemical results dovetail. In particular, we have obtained evidence suggesting that a switch in the order of states occurs at chain lengths of about Si₆ to Si₁₀. Shorter chains are believed to have a $^{1}\sigma\pi^{*}$ state and the longer ones a $^{1}\sigma\sigma^{*}$ state as the lowest excited singlets with obvious implications for spectroscopy, photophysics, and photochemistry. However, although reasonably advanced, the degree of understanding of these fascinating materials is still far from complete and the work is being continued. The current state of knowledge has been summarized in a comprehensive review [23].

In addition to results that have already been submitted for publication. further results are still being analyzed now. In particular, although some of the mysteries of the photophysics of oligosilanes have been resolved (e.g., what appeared to be a low-temperature conformational form of $\rm Si_{16}Me_{34}$ was demonstrated to be due to an aggregate which forms even in highly dilute solutions - true conformational effects have now also been found), several baffling observations remain to be explained, and in collaboration with Prof. West, we are continuing our efforts to understand simple model compounds such as $\rm Si_{16}Me_{34}$.